Simulating multiscale gated field emitters - a hybrid approach
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Multi-stage cathodes are promising candidates for field emission due to the multiplicative effect in local field predicted by the Schottky conjecture and its recent corrected counterpart [J. Vac. Sci. Technol. B 38, 023208 (2020)]. Due to the large variation in length scales even in a 2-stage compound structure consisting of a macroscopic base and a microscopic protrusion, the simulation methodology of a gated field emitting compound diode needs to be revisited. As part of this strategy, the authors investigate the variation of local field on the surface of a compound emitter near its apex and find that the generalized cosine law continues to hold locally near the tip of a multi-scale gated cathode. This is used to emit electrons with appropriate distributions in position and velocity components with a knowledge of only the electric field at the apex. The distributions are consistent with contemporary free-electron field emission model and follow from the joint distribution of launch angle, total energy, and normal energy. For a compound geometry with local field enhancement by a factor of around 1000, a hybrid model is used where the vacuum field calculated using COMSOL is imported into the Particle-In-Cell code PASUPAT where the emission module is implemented. Space charge effects are incorporated in a multi-scale adaptation of PASUPAT using a truncated geometry with 'open electrostatic boundary' condition. The space charge field, combined with the vacuum field, is used for particle-emission and tracking.

I. INTRODUCTION

The revival of interest in the century-old Schottky Conjecture (SC)10 and its recent experimental demonstration using the field emission data from a suitably constructed compound cathode19 point towards the potential utility of the multiplicative effect in constructing electron guns. The Schottky conjecture essentially states that if a protrusion exists on top of a large curved base, the electrostatic field enhancement factor at the tip of the protrusion is the product of the individual apex enhancement factors of the base ($\gamma_a^{(1)}$) and the protrusion ($\gamma_a^{(2)}$), provided the protrusion is sufficiently small. Its utility has been recently enhanced by the Corrected Schottky Conjecture (CSC) which accounts for situations when the protrusion is not very small and states that the apex enhancement factor at the tip of the compound structure, $\gamma_a^{(C)} = \gamma_a^{(2)} \langle \gamma_a^{(1)} \rangle$ where $\langle \ldots \rangle$ denotes the average enhancement over the height of the protrusion. In the limiting case when the protrusion is infinitesimally small $\langle \gamma_a^{(1)} \rangle = \gamma_a^{(1)}$ so that $\gamma_a^{(C)} = \gamma_a^{(2)} \gamma_a^{(1)}$, while as the height of the protrusion becomes large $\langle \gamma_a^{(1)} \rangle << \gamma_a^{(1)}$ and the effect of multiplication tends to vanish. Both the SC and the CSC deal with situations when the anode is placed far away. It has recently been verified21 that the CSC in fact holds even when the anode is in close proximity.

In order to make use of the multi-stage cathode in constructing devices, it is important that the multiplicative effect continues to hold in gated structures. Assuming that it does, the enhanced local electrostatic field can aid field emission by lowering the turn-on fields and generating high current densities at moderate applied macroscopic fields. Clearly, there is a need to study all aspects of field emission from gated compound structures.

The evaluation of the net field emission current requires us to know the local field normal to the surface of the emitter in the vicinity of the apex. While this can be easily determined using a finite element code such as COMSOL, most Particle-In-Cell (PIC) codes use finite differencing algorithms due to the ease in implementing Maxwell’s equations consistently. A high aspect ratio field emitter thus requires a lot of resources in dealing with the emission process since local fields on the curved surface near the emitter apex must be determined accurately.22 A way around this difficulty is to find only the field at the apex accurately and use analytical results for smooth parabolic tips to emit electrons or macro-particles having the correct distribution in position and velocity. This approach relies on the ‘universal’ generalized cosine law of local field variation for locally parabolic tips. It states that for an axially symmetric emitter described by $z = z(\rho)$, the electric field on the surface near the apex21

$$E(\rho) = E_a \frac{z/h}{\sqrt{z/h^2 + (\rho/R_a)^2}} = E_a \cos \tilde{\theta}$$  \hspace{1cm} (1)$$

where $E_a$ is the field at the apex, $h$ is the height of the emitter and $R_a$ is the radius of curvature at the apex. Thus, if the field at the apex is known, the cosine law can be used to determine the net field emission current ($I_{MG}$) within the Fowler-Nordheim14 and Murphy-Good15 formalisms. Importantly, for purposes of simulation, the cosine law can also be used to determine the joint distribution $f(\theta, \tilde{\theta})$ and $f(E_N, \tilde{E}_N)$ from the joint distribution $f(\theta, E_N, \tilde{E}_T)$ where $E_N$ and $\tilde{E}_T$ are the normal and total energies of the electrons. These distributions can thus be used to launch particles with the distributions in $\rho$ (equivalently $\theta$ or $z$)

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and the velocity components \(v_x, v_y\) and \(v_z\). The emission process can thus be handled without using up precious resources required for simulating the rest of the domain. Field emission from gated multi-stage compound cathodes can similarly be simulated if the generalized cosine law is found to hold.

The importance of a compound cathode stems from the fact that a high local field enhancement requires the ratio \(h/R_a\) to be large. For an isolated emitter, with the anode and other emitters far away from its neighborhood, the apex field enhancement factor (AFEF) \(\gamma_a = E_a/E_0\) is expressed as:

\[
\gamma_a = \frac{2h/R_a}{\alpha_1 \ln(4h/R_a) - \alpha_2}
\]

where \(\alpha_1, \alpha_2\) are constants for a particular geometry\[25\]. \(h\) is the height of the emitter and \(R_a\) is its apex radius of curvature. The local field at the apex \(E_a = \gamma_a E_0\) where \(E_0\) is the applied or macroscopic field. In a parallel plate geometry with a curved emitter mounted on the cathode plate, \(E_0 = V_g/D\) where \(V_g\) is the potential difference across the diode and the \(D\) is the plate separation. Clearly, a high field enhancement requires the structure to be tall and sharp. For a fixed apex radius of curvature \(R_a\), a single tall structure is mechanically unstable while a compound multi-stage cathode of the same height and apex radius of curvature is more stable and can achieve the desired field enhancement. A multi-stage construction is thus desirable.

A. Compounding and local field multiplication

For the 2-stage multiscale compound cathodes considered here, the apex field enhancement factor \(\gamma_a^C\) is calculated using COMSOL. For purposes of using SC or CSC, the individual enhancement factors of the base \((\gamma_a^{(1)})\) and the protrusion \((\gamma_a^{(2)})\) are also determined using COMSOL under identical gate conditions including the aperture radius \(R_g\). Thus, for calculating \(\gamma_a^{(1)}\), the protrusion is removed keeping the rest of the geometry unchanged, while for evaluating \(\gamma_a^{(2)}\), the protrusion is placed directly on the cathode plate and the gate is kept at a distance \(D - h_1\) from the cathode plate. In each case, convergence is ensured by varying the mesh parameters in COMSOL.

In order to ascertain the multiplicative enhancement of local field, consider a curved axially symmetric primitive base having a height \(h_1 = 50\text{mm}\) and base radius \(b_1 = 5\text{mm}\) shaped as a hemiellipsoid. It is placed in a gated configuration as shown in the Fig. with the gate placed at a distance \(D = 51\text{mm}\) from the cathode plate and having an aperture of radius \(R_g = 1\text{mm}\). The axis of the hemiellipsoid passes through the centre of the gate-aperture. Since the primitive base is an hemiellipsoid, its apex radius of curvature \(R_a^{(1)} = b_1^2/h_1 = 0.5\text{mm}\). At the next stage, we place another hemiellipsoid (protrusion or crown) of base radius \(b_2 = 0.1\mu\text{m}\) which is small compared to \(R_a^{(1)}\). The height of the protrusion \(h_2\) is varied from 0.1mm to 1mm.

The variation of the apex field enhancement factor of the compound structure normalized to that of the primitive base is shown in Fig. 2. The solid squares are the
values of \( \gamma_a^{(C)}/\gamma_a^{(1)} \) where \( \gamma_a^{(C)} \) and \( \gamma_a^{(1)} \) are the AFEF of the compound structure and the primitive base respectively. Also shown alongside is the AFEF of the protrusion \( \gamma_a^{(2)} \) using solid circles. Note that \( \gamma_a^{(1)} \) is evaluated keeping the separation between the plates \( (D) \) as in the compound structure, while \( \gamma_a^{(2)} \) is evaluated keeping the distance between the gate and cathode plate as \( D - h_1 \).

Clearly, a value \( \gamma_a^{(C)}/\gamma_a^{(1)} > 1 \) shows the multiplicative effect. Indeed, for small \( h_2 \), the multiplication factor coincides with the AFEF of the protrusion on top of the base. This is consistent with the Schottky conjecture. As \( h_2 \) increases, the multiplication factor drops below the value of the AFEF of the protrusion \( (\gamma_a^{(2)}) \), consistent with the expectation from the Corrected Schottky Conjecture.

The multiplicative effect can be alternately presented to show how a pre-fabricated protrusion benefits by being placed on top of a base. We thus plot \( \gamma_a^{(C)}/\gamma_a^{(2)} \) for the same geometry in Fig. 3. The base is held at a fixed height \( h_1 = 50\text{mm} \) while the height of the protrusion is varied. A long protrusion (e.g. \( h_2/R_a^{(1)} = 2 \)) also enjoys the enhancement of the base in a gated structure, albeit with a reduced multiplicative effect.

### B. Predictions of SC and CSC for gated structures

It is thus clear that multi-stage gated cathodes can be used to enhance the local field. We shall now briefly study the errors in prediction of \( \gamma_a^{(C)} \) using the Schottky Conjecture and the Corrected Schottky Conjecture. Since the radius of the gate aperture changes the local field at the apex of the compound structure, the predictive capabilities of SC and CSC under different gate conditions also need to be investigated.

Consider thus a primitive hemiellipsoid base of height \( 50\text{mm} \) and base radius \( 5\text{mm} \). The protrusion is also a hemiellipsoid with base \( 0.1\text{mm} \) and its height \( h_2 \) is varied from \( 0.025\text{mm} \) to \( 1\text{mm} \). The gate radius is kept fixed at \( R_g = 1\text{mm} \). Fig. 4 shows respectively the relative error in SC and CSC predictions for gate placed at a distance \( D = 51\text{mm} \) and \( D = 52\text{mm} \) from the cathode plane.

The relative error for the Schottky conjecture is defined as \( 100 \times |\gamma_a^{(C)} - \gamma_a^{(1)}/\gamma_a^{(1)}|/\gamma_a^{(C)} \) while in case of...
the Corrected Schottky Conjecture, the relative error is

\[ 100 \times |\langle \gamma_a^{(C)} \rangle - \langle \gamma_a^{(1)} \rangle \gamma_a^{(2)} | / \langle \gamma_a^{(C)} \rangle \]

where

\[ \langle \gamma_a^{(1)} \rangle = \frac{1}{E_0} \int_{h_1}^{h_1+h_2} E_z(z) \, dz \]  

(3)

is the average field enhancement on the axis over the height of the protrusion \( h_2 \). Clearly, for both gate positions, the CSC performs well while the SC is comparable or performs better for very small protrusions. Note that while the gate position \( D \) and aperture radius \( R_g \) have an effect on the relative error in both the SC and CSC prediction, the CSC in general performs much better in all the cases studied.

We can thus conclude that the multiplicative effect is pronounced in a multi-scale cathode and the Corrected Schottky Conjecture can be reliably used to predict the apex field enhancement factor.

III. LOCAL FIELD VARIATION AND THE COSINE LAW

We shall now study the variation of surface local field near the apex of the multi-scale compound structure. As in section II, we shall consider a hemiellipsoid protrusion on top of a hemiellipsoid base as an example. In addition, we shall also consider an HECP (hemiellipsoid on a cylindrical post) protrusion on a hemiellipsoid base.

![FIG. 5. The variation in the local field normalized to the field at the apex of the protrusion (denoted by \( E_a \)) along the surface of the protrusion in a 2-stage compound geometry comprising of 2 hemiellipsoids. Here \( R_a = \text{R}_a^{(2)} \) denotes the apex radius of curvature of the compound geometry. The protrusion height \( h_2 = 0.5 \text{mm} \) while \( D = 5 \text{mm} \). Inset shows part of the ellipsoid-base and the protrusion.](image)

Note that the generalized cosine law of Eq. (1) was first derived analytically for a hemiellipsoid with the anode far away. It was also shown to hold numerically for other shapes and with the anode in close proximity. It was subsequently established analytically using the nonlinear line charge model that the cosine law holds approximately for sharp parabolic emitters \( (h/R_a >> 1) \).

While a multistage cathode is expected to have a nonlinear line charge density, it may not be smooth at the junction of two stages. It is thus necessary to ascertain the validity of the generalized cosine law of local field variation.

Fig. 5 shows the variation on the surface of a hemiellipsoid protrusion of height \( h_2 = 0.5 \text{mm} \), base radius \( b_2 = 0.1 \text{mm} \), placed on a hemiellipsoid base of height \( h_1 = 50 \text{mm} \) and base radius \( b_1 = 5 \text{mm} \). The apex radius of curvature of the apex is \( R_a^{(2)} = 0.02 \text{mm} \). The scaled field is plotted till \( \rho = 1.25R_a^{(2)} \) since field emission is generally negligible for \( \rho > R_a \).

Clearly, the local field follows the generalized cosine law very well. A similar observation holds for other aperture radius such as \( R_g = 0.25 \text{mm} \). Fig. 6 shows the cosine law for a smaller protrusion of height \( h_2 = 0.2 \text{mm} \) at \( R_g = 0.25 \text{mm} \). The local field follows the generalized cosine law of Eq. (1) fairly well for \( \rho < 0.8R_a \) but deviates thereafter. While this is likely to induce only small errors in the field emission current for moderate fields, the cause of the deviation from the cosine law is likely the effect of smaller gate aperture and height of protrusion resulting in a sharp change in line charge density near the top of the base.

![FIG. 6. As in Fig. 5 for \( h_2 = 0.2 \text{mm} \) and \( R_g = 0.25 \text{mm} \). Deviation from the cosine law occurs for \( \rho > 0.8R_a \). The inset shows the hemiellipsoid protrusion and the endcap of the hemiellipsoid base.](image)

We next consider an HECP protrusion on a hemiellipsoid base. The HECP has a total height \( h_2 = 0.5 \text{mm} \). The cylindrical post has a radius 0.05mm and height 0.3mm. The ellipsoid cap on HECP thus has a height 8 times the apex radius of curvature. The variation of the local field is shown in Fig. 7 (solid line) along with the generalized cosine law. The agreement is good. As the height of the hemi-ellipsoid endcap becomes smaller than about five times the apex radius of curvature and tends towards a hemispherical endcap, deviations from the cosine law become larger.
FIG. 7. The variation in local field for an HECP protrusion for $h_2 = 0.5$mm comprising of a cylindrical post of height 0.3mm, radius = 0.05mm and a hemiellipsoid endcap of height 0.2mm and base radius 0.05mm. Here $D = 51$mm and the gate radius $R_o = 1$mm. The inset shows the HECP protrusion and the endcap of the hemiellipsoid base.

IV. FIELD EMISSION FROM A COMPOUND CATHODE AND PARTICLE TRACKING

It is thus clear that a compound emitter with a locally parabolic endcap follows the generalized cosine law provided the endcap is not too close to the junction of two stages. This can be used to determine the net emission current using the electric field and the radius of curvature at the emitter apex. The net field emission current from the endcap using the local current density is given by

$$I_{MG} = \int_0^{R_o} d\rho \ J_{MG}(\rho) \ 2\pi\rho \sqrt{1 + \left(\frac{dz}{d\rho}\right)^2}$$

where the Murphy-Good expression for the current density

$$J_{MG}(\rho) = \frac{A_{FN} \ E^2(\rho)}{t_F(\rho) - \phi} \ \exp(-v_F(\rho)B_{FN}\phi^{3/2}/E(\rho))$$

is used and the field variation follows the generalized cosine law

$$E(\rho) = E_a \ \frac{z/h}{\sqrt{(z(\rho)/h)^2 + (\rho/R_o)^2}}$$

Here, $A_{FN} \approx 1.541434 \ \mu A \ eV^{-2}$ and $B_{FN} \approx 6.830890 \ eV^{-3/2} \ V^{-1}$ are the conventional Fowler-Nordheim constants, while $v_F(\rho) = 1 - f(\rho) + (f(\rho)/6) \ln f(\rho)$, $t_F(\rho) = 1 + f(\rho)/9 - (f(\rho)/18) \ln f(\rho)$ are corrections due to the image-charge potential with $f(\rho) = 1.439965E(\rho)/\phi^2$. We shall assume the workfunction $\phi = 4.5$eV hereafter. Note that in Eq. $[6]$, $z = h - \rho^2/(2R_o)$ for a locally parabolic tip.

For purposes of simulation, the net current must be generated by appropriate distributions of emitted electrons from the surface. For sharp emitters, the distribution

$$f(\theta) d\theta \simeq \frac{2\pi R_o^2}{\cos^2 \theta} \sin \theta A_{FN} E_a^2 \exp\left(-\frac{\rho_{FN}\theta}{E_a \ \phi}\right) - \frac{3/2}{(E_a \ \cos \theta)} d\theta$$

(7)

can be used to determine the current

$$\Delta I = \int_0^{\theta + \Delta \theta} f(\theta) d\theta$$

(8)

emitted between $\theta$ and $\theta + \Delta \theta$ from the surface of the emitter tip. In Eq. $[7]$, the free electron model is assumed, barrier lowering due to the image potential is incorporated and it is assumed that the surface near the apex has a uniform workfunction $\phi$.

Note that the $\rho$ and $\theta$ are related through Eq. $[1]$ so that the distribution can equivalently be expressed in terms of $\rho$. For sharp parabolic emitters $(R_o/h << 1)$, $\rho \approx R_o \ \tan \theta$. Using this relation between $\rho$ and $\theta$, it follows that the angle $\theta_L$ that the normal (at any point $\rho$ on the parabolic surface $z = h - \rho^2/(2R_o)$) makes with the emitter axis, is such that $\tan \theta_L = \rho/R_o \approx \tan \theta$. Thus, $\theta_L \approx \theta$ so that $f(\theta)$ also describes the distribution of launch angles ($\theta_L$) of electrons from the surface of a parabolic emitter.

Having generated a value of $\theta$ using the distribution in Eq. $[6]$, a value for the normal energy $E_N$ and total energy $E_T$ can be generated using the distributions $f(E_N, \theta)$ and $f(E_T|E_N, \theta)$, both of which can be arrived at using the joint distribution $f(\theta, E_N, E_T)$. Thus the velocity components in a local co-ordinate system centred at $(\rho(\theta), z(\theta))$ on the surface of the emitter can be found using $\theta$, $E_N$ and $E_T$. For a given simulation timestep $\Delta T$, the net charge emitted from $\theta$ and $\theta + \Delta \theta$ is $\Delta Q = \Delta I \Delta t$. The charge $\Delta Q$ can be distributed among a number of macro-particles with a distribution of velocities.

The algorithm described above has been incorporated in the Particle-In-Cell code PASUPAT which allows emission of electrons (macroparticles with variable weight in general) from the endcap of the structures with a knowledge of only the apex electric field $E_a$. For a compound multi-scale geometry such as the one considered here, the local field around the apex of is up to three orders of magnitude higher than the macroscopic field $(\sim V_y/D)$. Thus, a Yee-Grid based finite difference approach is not feasible for the entire triode region, comprising of the cathode plate with the compound emitter, the gate and the anode. This is especially so due to the enormous resources required for accurate tracking of the...
particles in the immediate neighbourhood of the emitter apex. Note that an error in the electrostatic field within about a distance $R_a$ from the apex can adversely affect energy conservation and the emittance. We shall therefore use a hybrid approach to study particle dynamics for such multiscale cathodes.

In the approach adopted here, the applied electrostatic vacuum field for the triode is evaluated separately using a finite element code. The electric field components are then imported to the PIC code PASUPAT where macro-particles are emitted using distributions $f(\theta)$, $f(E_\perp|\theta)$ and $f(E_T|\theta,E_N)$. The hemiellipsoid protrusion is shown in full while only the top portion of the hemiellipsoid-base is visible. The parameters used are $D = 52mm$, $h_2 = 0.5mm, b_2 = 0.1mm$, $h_1 = 50mm$, $b_1 = 5mm$ and $R_g = 1mm$. At each time step 500 macro-particles are emitted. The anode and gate are grounded while the cathode is at a potential $V_g = -260V$. The field at the apex of the protrusion is $E_a \simeq 3.79V/nm$.

![Figure 8](image_url)

**FIG. 8.** A PIC simulation of a compound emitter using PASUPAT where macro-particles are emitted using distributions $f(\theta), f(E_\perp|\theta)$ and $f(E_T|\theta,E_N)$. The hemiellipsoid protrusion is shown in full while only the top portion of the hemiellipsoid-base is visible. The parameters used are $D = 52mm$, $h_2 = 0.5mm, b_2 = 0.1mm$, $h_1 = 50mm$, $b_1 = 5mm$ and $R_g = 1mm$. At each time step 500 macro-particles are emitted. The anode and gate are grounded while the cathode is at a potential $V_g = -260V$. The field at the apex of the protrusion is $E_a \simeq 3.79V/nm$.

In the approach adopted here, the applied electrostatic vacuum field for the triode is evaluated separately using a finite element code. The electric field components are then imported to the PIC code PASUPAT where a truncated geometry is used with $z \geq z_T$. Thus for the 2-stage multiscale cathode having a hemiellipsoid protrusion of height $h_2 = 0.5mm$ on a hemiellipsoid base of height $h_1 = 50mm$, the truncated geometry simulated corresponds to $z \geq z_T$ with $z_T = 49.495mm$. The geometry simulated (in PASUPAT) therefore consists of the base-endcap, the protrusion, the gate and the anode. The mesh chosen is fine enough for accurate tracking but too coarse for field emission. After particle emission begins, space charge effects are evaluated separately by solving Poisson equation with all conductors grounded and ‘open electrostatic boundary’ condition imposed on the plane $z = z_T$ excluding the portion occupied by the base-endcap which is a conductor. The space charge field is then added to the applied field and used for subsequent emission at the next time-step and for particle tracking. Fig. 5 shows a typical beam-optics simulation using PASUPAT where particles are emitted and tracked using the methodology described. The colour scale shows the speed multiplied by the relativistic factor ‘gamma’. In this case, space charge effects do not significantly affect the emission current and only mildly affects the beam as it passes through the gate aperture ($R_g = 1mm$).

![Figure 9](image_url)

**FIG. 9.** The gate current for gate radius $R_g = 0.25mm$ and $D = 52mm$, with and without space charge effect. The gate loss increases when space charge effect is turned on. The field at the apex of the protrusion is $E_a \simeq 3.85V/nm$.

As the gate aperture is reduced, the vacuum apex field increases. While the space charge field at the apex is not strong enough to affect the emitted current significantly, the gate current loss increases when space charge effect is switched on. This can be seen in Fig. 9 where the locally time-averaged gate current (the current lost at the gate) with and without space charge effects is shown for $D = 52mm$ with $R_g = 0.25mm$.

Finally, Fig. 10 shows the emitted current for different gate aperture radius $R_g$ for a hemi-ellipsoid protrusion with $h_2 = 0.5mm$ and $b_2 = 0.1mm$ on a hemiellipsoid base with $h_1 = 50mm$ and $b_1 = 5mm$. The compound emitter and cathode plates are kept at a potential $V_g = -E_0D$ where $E_0 = 5 \times 10^6 V/m$. The variation in emitted current as the gate aperture $R_g$ is varied is shown for 2 different gate locations $D = 51.5mm$ and $D = 52mm$. Clearly, the emitted current decreases with an increase in gate aperture and distance from the tip of the apex of the compound structure. Note that space charge effects do not significantly alter the emitted current for $D = 52mm$ and has only a mild effect for $D = 51.5mm$ for small gate apertures.

V. DISCUSSIONS AND CONCLUSIONS

We have demonstrated a methodology to simulate field emission from compound multi-stage emitters using a hybrid approach (such as in Ref [37]) wherein a combination of analytical and numerical methods can be used to emit...
and track particles in the gated diode region. We have further adapted this approach to include space charge effects using a truncated geometry with ‘open electrostatic boundary condition’.

Crucial to this task was the demonstration that the generalized cosine law of local field variation on the surface of locally parabolic tips, continues to hold in multi-stage emitters. This enables us to use the results for the net current distributions of electrons in position and velocity and emit macroparticles from the protrusion where the local field is high. Note that the requirement of a locally parabolic tip excludes protrusions with hemi-spherical endcaps but is otherwise generic. Also, the base of the axially symmetric multiscale emitter can assume shapes other than the hemiellipsoid considered here. Our numerical investigations also show that the Corrected Schottky Conjecture performs well in predicting the apex field enhancement factor for compound emitters in a gated diode and can be used for predicting field emission currents with reasonable accuracy.

While the simulation methodology for multiscale emitters developed here is sufficiently general, we have restricted ourselves to problems where space charge does not alter the apex field substantially. The use of distributions to emit electrons requires the generalized cosine law to hold in the presence of space charge arising from field emission. It thus needs to be independently established that the cosine law holds at moderate to high vacuum field strengths where the current emitted is much larger.

**Author Credits** — S.S carried out the COMSOL simulations on corrected Schottky conjecture and generalized cosine law; R.K. and G.S. adapted PASUPAT for multi-stage cathodes and performed the simulations; D.B. conceived the idea, devised the methodology, supervised the work; all authors contributed to the manuscript.

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**Data Availability:** The computational data that supports the findings of this study are available within the article.

**VI. REFERENCES**

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25. For a hemiellipsoid emitter, $\alpha_1 = 1$ and $\alpha_2 = 2$ when $h/R_0 \geq 50$.
26. The Corrected Schottky Conjecture may perform better for certain gated structures when the averaging interval is reduced, for instance for $h_2$ to $3h_2/4$.
The line charge density can be arrived at by projecting the surface charge density which in turn can be determined from the normal electric field on the surface of the emitter in a numerical calculation. For an example see Ref. [28]. A nonlinear line charge density has been observed experimentally in Ref. [29].

Corrections to the distribution $f(\tilde{\theta})$ and the launch angle need to be incorporated for emitters that are not sharp. Eq. (7) is adequate for emitters with apex field enhancement factors greater than fifty.

PASUPAT has been benchmarked using standard problems. It reproduces the Child-Langmuir law for planar diode, both for the finite and infinite emission area and correctly predicts the electromagnetic power loss from open diodes [33]. It has recently been used to verify the linear scaling of space charge limited current with the apex field enhancement factor [34].


